NSN 5962-00-225-5325

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View Online at https://aerobasegroup.com/nsn/5962-00-225-5325 **Body Length:** 1.250 inches **Body Width:** 0.520 inches **Body Height:** 0.160 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -25.0/+70.0 degrees celsius **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** P-type metal oxide-semiconductor logic **Input Circuit Pattern:** 12 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -0.3 volts power source and 20.0 volts power source **Time Rating Per Chacteristic:** 1000.00 nanoseconds propagation delay time, low to high level output and 1000.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Test Data Document:** 24930-g390406 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a

Yes - demil/mli

Unit Of Measure:

Demilitarization:

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